PG201 THRU PG210 2.0 AMP SILICON RECTIFIERS **VOLTAGE RANGE** 50 to 1000 Volts CURRENT **FEATURES** 2.0 Amperes * Low forward voltage drop * High current capability DO-15 * High reliability À * High surge current capability .140(3.6) * Both normal and Pb free product are available: .104(2.6) DIA * Normal:80~95%Sn,5~20%Pb 1.0(25.4) * Pb free:99 Sn above can meet Rohs enviroment substance MIN. directive request **MECHANICAL DATA** ⊻ * Case: Molded plastic .300(7.6) * Epoxy: UL 94V-0 rate flame retardant .230(5.8) * Lead: Axial leads, solderable per MIL-STD-202, method 208 guranteed * Polarity: Color band denotes cathode end 1.0(25.4) * Mounting position: Any .031(.8) MIN. * Weight: 0.40 grams .024(.6) DIA. ۲ Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature uniess otherwies specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

TYPE NUMBER	PG201	PG202	PG203	PG204	PG206	PG208	PG210	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current								
.375"(9.5mm) Lead Length at Ta=75 °C	2.0							A
Peak Forward Surge Current, 8.3 ms single half sine-wave								
superimposed on rated load (JEDEC method)	70						A	
Maximum Instantaneous Forward Voltage at 2.0A		1.0					V	
Maximum DC Reverse Current Ta=25 °C	5.0						μA	
at Rated DC Blocking Voltage Ta=100℃		50						
Typical Junction Capacitance (Note 1)		20						pF
Typical Thermal Resistance R0JA (Note 2)		40					°C/W	
Operating and Storage Temperature Range TJ, Tstg		-65-+150						

NOTES:

1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal Resistance from Junction to Ambient .375" (9.5mm) lead length.

